

Form PTO-1449		Docket Number (Optional)	Application Number
O P E R A T I O N INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)		HALO-02-003	10/685,873
		Applicant	Seiki Ogura et al.
		Filing Date	10/15/03
		Group Art Unit	

FOREIGN PATENT DOCUMENTS

	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	Translation	
						YES	NO

OTHER DOCUMENTS (Including Author, Title, Date, Permanent Pages, Etc.)

T. D	-	S. Minami et al., "A Novel MONOS Nonvolatile Memory Device Ensuring 10-Year Data Retention after 10^7 Erase/Write Cycles", <u>IEEE Trans. on Electron Device</u> , Vol. 40, No.11, Nov. 1993, pp. 2011-2017.
T. D	-	E. Suzuki et al., "Hole and Electron Current Transport in Metal-Oxide-Nitride-Oxide-Silicon Memory Structures", <u>IEEE Trans. on Electron Device</u> , Vol. 36, No.6, June 1989, pp. 1145-1149.

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

